

400mW SOD-123 Plastic Encapsulated Diodes

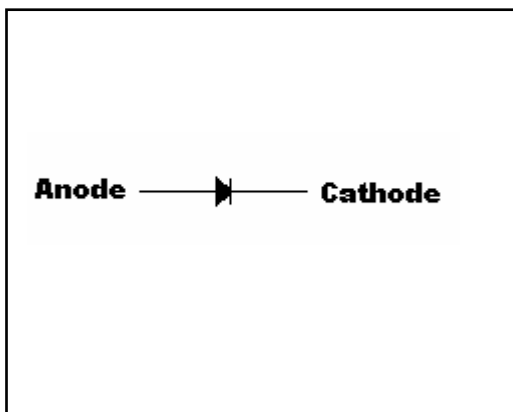
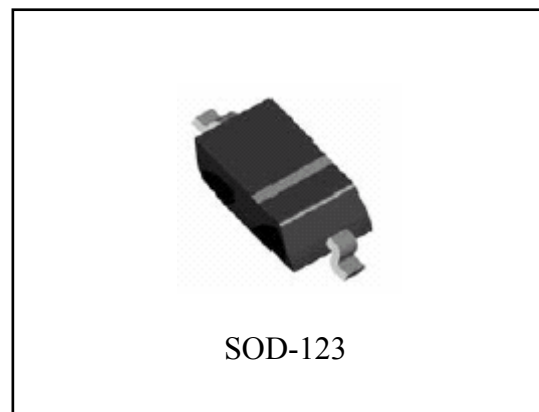
1N4448WSH

Features:

- Fast switching speed
- Surface mount package suitable for automatic insertion
- For general purpose switching applications
- High conductance

Mechanical Data

- Case : SOD-123 , molded plastic
- Terminals : Solderable per MIL-STD-750 method 2026
- Polarity : Cathode indicated by polarity band.
- Flammability rating : UL94 V-0
- Package weight : approx. 0.01 gram/unit
- Mounting position : Any

Symbol**Outline**

**Maximum Ratings**($T_A=25^{\circ}\text{C}$, unless otherwise noted)

| Characteristics | Symbol | Value | Unit |
|--|-----------|-------------|--------------------|
| Non-Repetitive Peak Reverse Voltage | V_{RM} | 100 | V |
| Repetitive Peak Reverse Voltage | V_{RRM} | 100 | V |
| DC Blocking Voltage | V_R | 100 | V |
| RMS Reverse Voltage | V_{RMS} | 70 | V |
| Forward Continuous Current | I_{FM} | 500 | mA |
| Average Forward Rectified Current | I_O | 250 | mA |
| Peak Forward Surge Current @ $t_p=1.0\mu\text{s}$ @ $t_p=1.0\text{s}$ | I_{FSM} | 4.0 | A |
| | | 2.0 | |
| Power Dissipation | P_D | 400 | mW |
| Junction Temperature | T_j | 125 | $^{\circ}\text{C}$ |
| Storage Temperature Range | T_{stg} | -65 to +150 | $^{\circ}\text{C}$ |

Maximum Thermal Resistance($T_A=25^{\circ}\text{C}$)

| Parameter | Test Conditions | Symbol | Value | Unit |
|--------------------------------|-----------------|-------------|-------|-----------------------------|
| Junction to Ambient Resistance | | $R_{th,JA}$ | 315 | $^{\circ}\text{C}/\text{W}$ |

Electrical Characteristics ($T_A=25^{\circ}\text{C}$, unless otherwise noted)

| Parameter | Conditions | Symbol | Min | Typ | Max | Unit |
|---------------------------|---|------------|------|-----|-------|---------------|
| Forward Voltage | $I_F=5\text{mA}$ | V_F | 0.62 | - | 0.72 | V |
| | $I_F=10\text{mA}$ | | - | - | 0.855 | |
| | $I_F=100\text{mA}$ | | - | - | 1.0 | |
| | $I_F=150\text{mA}$ | | - | - | 1.25 | |
| Reverse Current | $V_R=20\text{V}$ | I_R | - | - | 25 | nA |
| | $V_R=100\text{V}$ | | - | - | 2.5 | μA |
| Reverse Breakdown Voltage | $I_R=10\mu\text{A}$ | $V_{(BR)}$ | 100 | - | - | V |
| Diode Capacitance | $V_R=0, f=1\text{MHz}$ | C_T | - | - | 4 | pF |
| Reverse Recovery Time | $I_F=I_R=10\text{mA}, I_{RR}=0.1 \times I_R, R_L=100\Omega$ | t_{rr} | - | - | 4 | ns |

Ordering Information

| Device | Package | Shipping | Marking |
|-----------|----------------------|------------------------|---------|
| 1N4448WSH | SOD-123 (Pb-free) | 3000 pcs / Tape & Reel | T4 |

Characteristic Curves

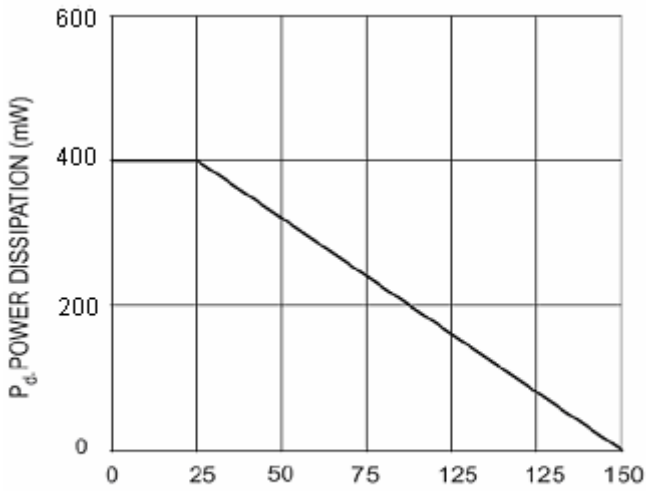


Fig. 1 Forward Current Derating Curve

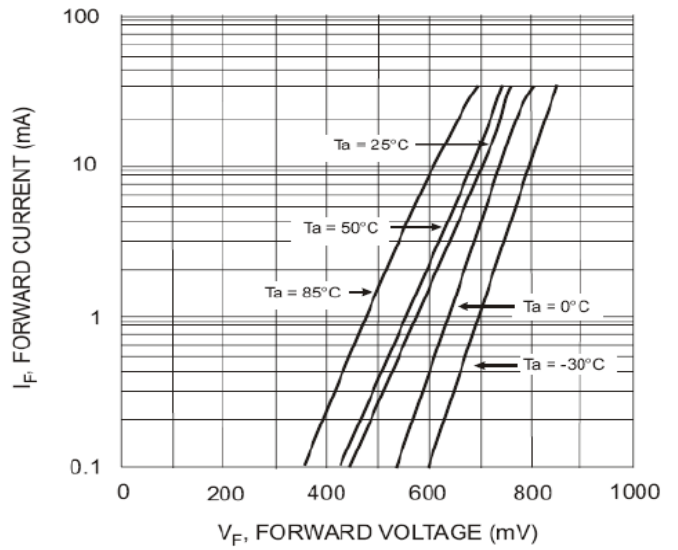


Fig. 2 Typical Forward Characteristics

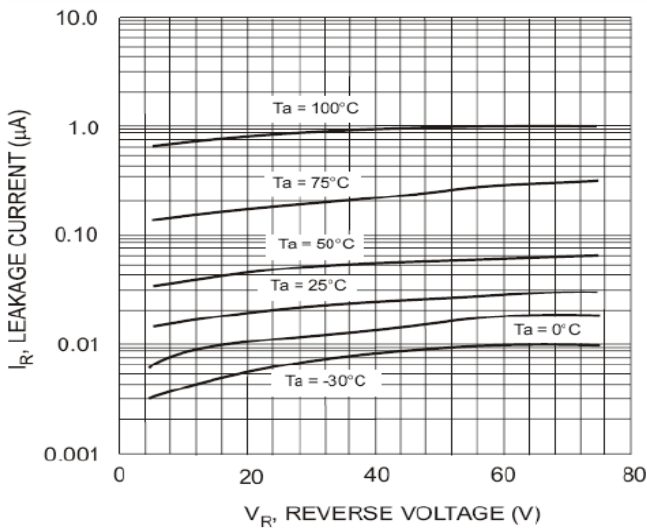


Fig. 3 Typical Reverse Characteristics

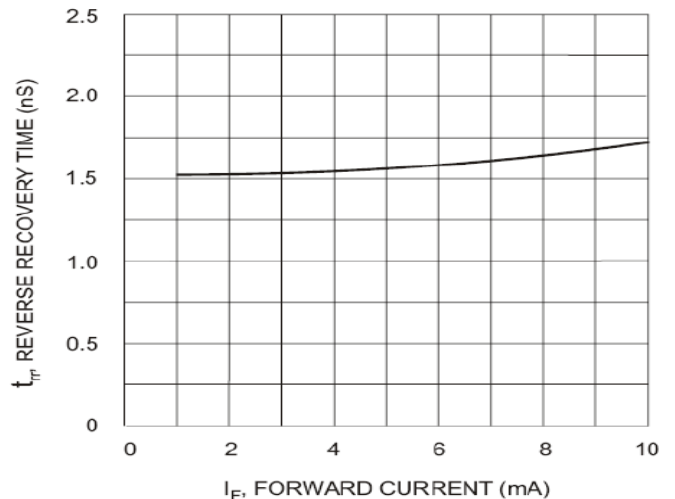


Fig. 4 Reverse Recovery Time vs. Forward Current

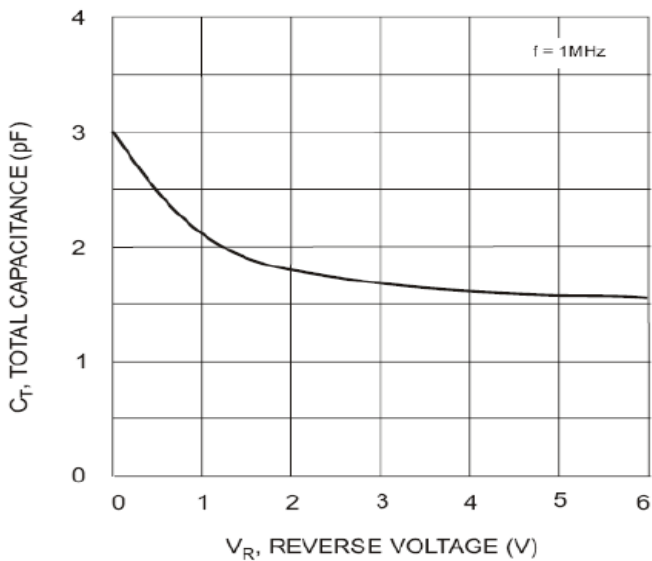
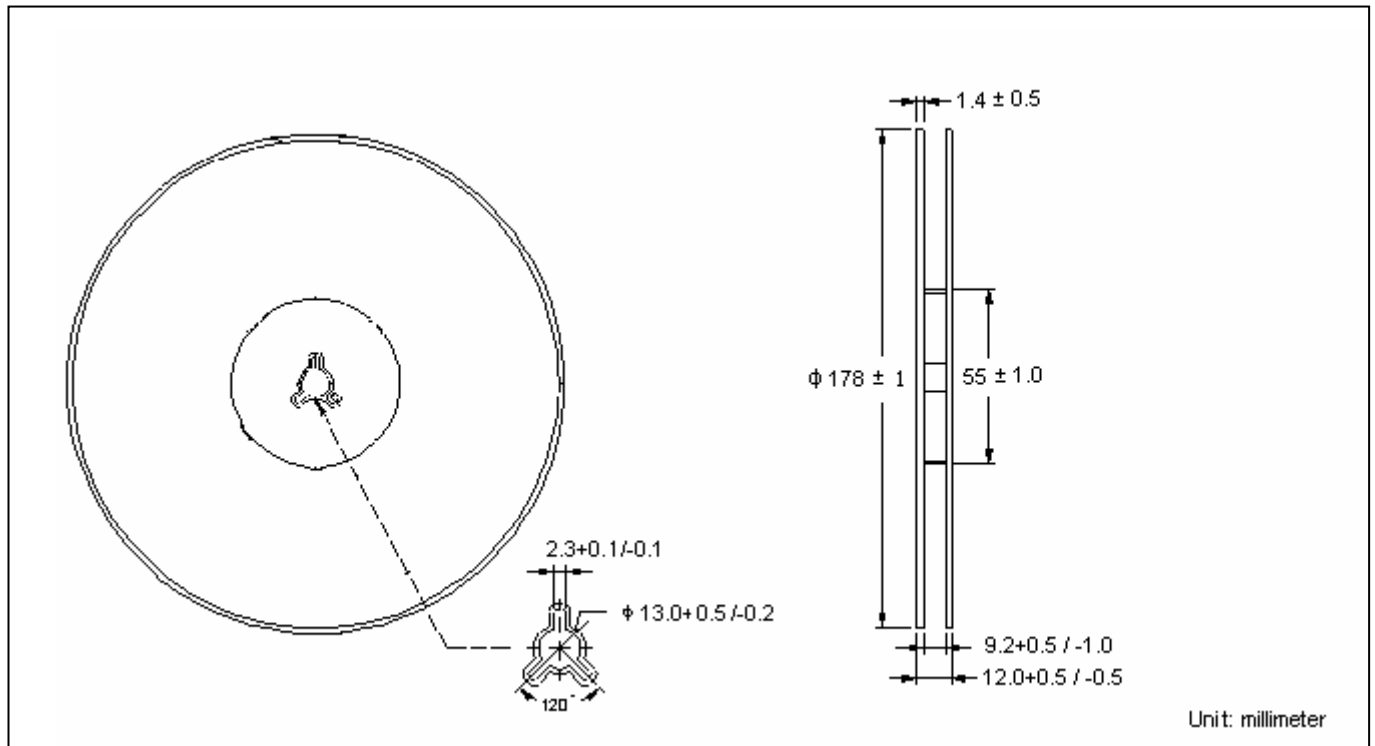
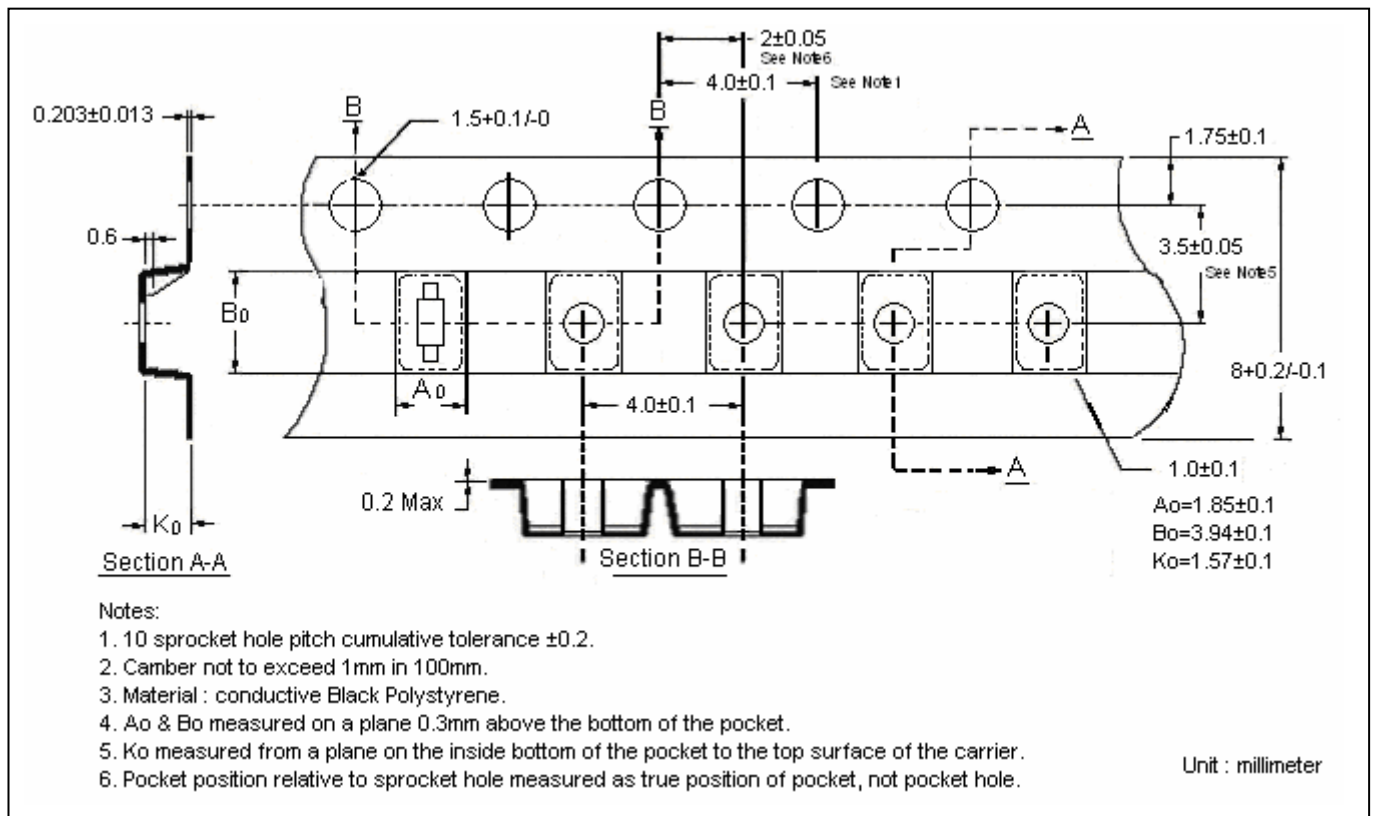


Fig. 5 Total Capacitance vs. Reverse Voltage

Reel Dimension



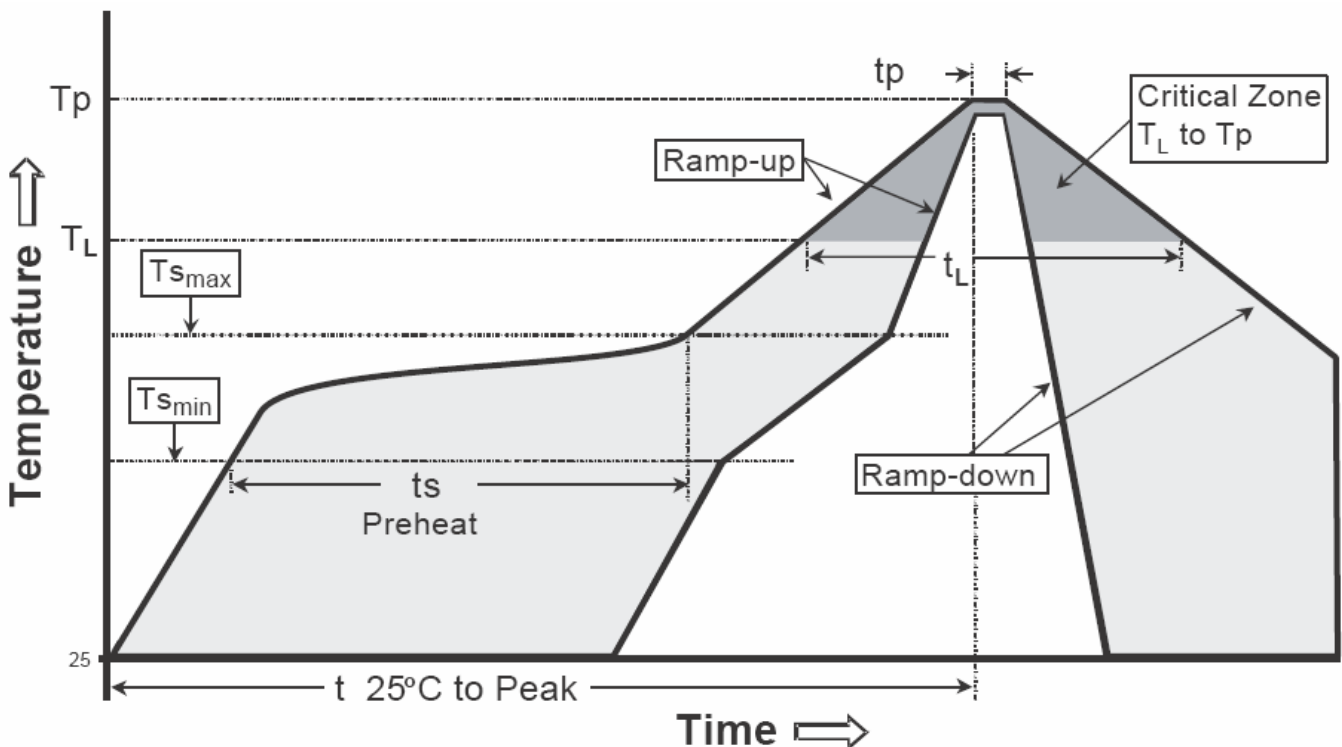
Carrier Tape Dimension



Recommended wave soldering condition

| Product | Peak Temperature | Soldering Time |
|-----------------|------------------|-----------------|
| Pb-free devices | 260 +0/-5 °C | 5 +1/-1 seconds |

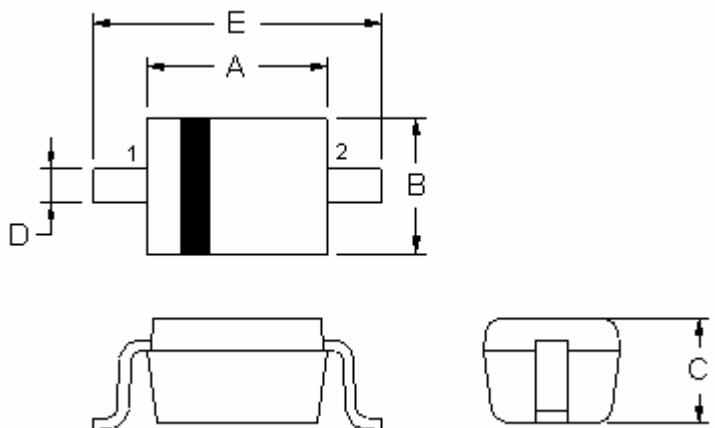
Recommended temperature profile for IR reflow



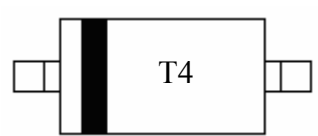
| Profile feature | Sn-Pb eutectic Assembly | Pb-free Assembly |
|---|-------------------------|------------------|
| Average ramp-up rate (T _{smax} to T _p) | 3°C/second max. | 3°C/second max. |
| Preheat | | |
| -Temperature Min(T _{s min}) | 100°C | 150°C |
| -Temperature Max(T _{s max}) | 150°C | 200°C |
| -Time(t _{s min} to t _{s max}) | 60-120 seconds | 60-180 seconds |
| Time maintained above: | | |
| -Temperature (T _L) | 183°C | 217°C |
| - Time (t _L) | 60-150 seconds | 60-150 seconds |
| Peak Temperature(T _P) | 240 +0/-5 °C | 260 +0/-5 °C |
| Time within 5°C of actual peak temperature(tp) | 10-30 seconds | 20-40 seconds |
| Ramp down rate | 6°C/second max. | 6°C/second max. |
| Time 25 °C to peak temperature | 6 minutes max. | 8 minutes max. |

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOD-123 Dimension



Marking:



Style: Pin 1.Cathode 2.Anode

2-Lead SOD-123 Plastic Surface Mounted Package
CYStek Package Code: SH

*: Typical

| DIM | Inches | | Millimeters | | DIM | Inches | | Millimeters | |
|-----|--------|-------|-------------|-------|-----|--------|-------|-------------|-------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Min. | Max. |
| A | 0.102 | 0.110 | 2.600 | 2.800 | E | 0.140 | 0.152 | 3.550 | 3.850 |
| B | 0.059 | 0.067 | 1.500 | 1.700 | | | | | |
| C | 0.041 | 0.049 | 1.050 | 1.250 | | | | | |
| D | 0.018 | 0.026 | 0.450 | 0.650 | | | | | |

Notes: 1.Controlling dimension : millimeters.
 2.Lead thickness specified per L/F drawing with solder plating.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

Important Notice:

- All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of CYStek.
- CYStek reserves the right to make changes to its products without notice.
- CYStek **semiconductor products are not warranted to be suitable for use in Life-Support Applications, or systems.**
- CYStek assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.